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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Bojarczuk, et al.

Serial No.: 09/755,164

Group Art Unit: 2826

Filed: January 8, 2001

Examiner: Quinto, Kevin V.

For: ALUMINUM NITRIDE AND ALUMINUM OXIDE/ALUMINUM NITRIDE
HETEROSTRUCTURE GATE DIELECTRIC STACK BASED FIELD EFFECT
TRANSISTORS AND METHOD FOR FORMING SAME

Honorable Commissioner of Patents
Box AF
Alexandria, VA 22313 - 1450

AMENDMENT AFTER FINAL REJECTION UNDER 37 C.F.R. §1.116

Sir:

In preparation for imminent appeal and in response to the Office Action dated July 16, 2003, please amend the above-identified application as follows:

INTRODUCTORY COMMENTS

Claims 1-7 and 14-18 are all the claims presently pending in the application. Claims 1-7, 14-15 and 17 have been amended to more clearly define the invention. Claims 1, 14-15 and 17 are independent.